

TOSHIBA Transistor Silicon NPN Epitaxial Type

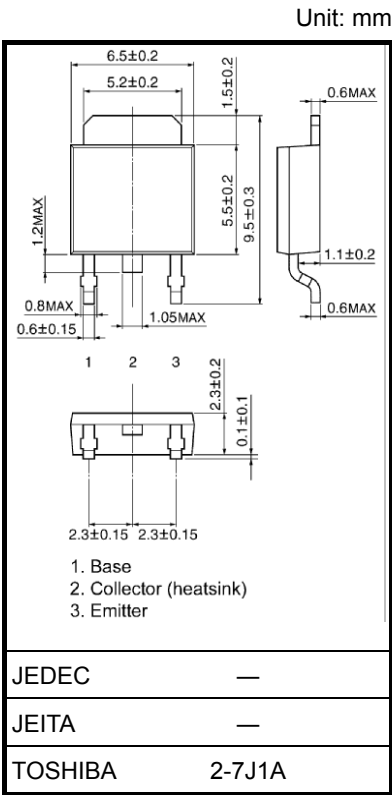
2SC5886

High-Speed Switching Applications
DC-DC Converter Applications

- High DC current gain: $h_{FE} = 400$ to 1000 ($I_C = 0.5$ A)
- Low collector-emitter saturation: $V_{CE(sat)} = 0.22$ V (max)
- High-speed switching: $t_f = 55$ ns (typ.)

Absolute Maximum Ratings ($T_a = 25^{\circ}\text{C}$)

Characteristics		Symbol	Rating	Unit
Collector-base voltage		V_{CBO}	100	V
Collector-emitter voltage		V_{CEX}	80	V
		V_{CEO}	50	
Emitter-base voltage		V_{EBO}	7	V
Collector current	DC	I_C	5	A
	Pulse	I_{CP}	10	
Base current		I_B	0.5	A
Collector power dissipation	$T_a = 25^{\circ}\text{C}$	P_C	1	W
	$T_c = 25^{\circ}\text{C}$		20	
Junction temperature		T_j	150	$^{\circ}\text{C}$
Storage temperature range		T_{stg}	-55 to 150	$^{\circ}\text{C}$



Weight: 0.36 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current		I_{CBO}	$V_{CB} = 100 \text{ V}, I_E = 0$	—	—	100	nA
Emitter cut-off current		I_{EBO}	$V_{EB} = 7 \text{ V}, I_C = 0$	—	—	100	nA
Collector-emitter breakdown voltage		$V_{(BR) CEO}$	$I_C = 10 \text{ mA}, I_B = 0$	50	—	—	V
DC current gain		$h_{FE} (1)$	$V_{CE} = 2 \text{ V}, I_C = 0.5 \text{ A}$	400	—	1000	
		$h_{FE} (2)$	$V_{CE} = 2 \text{ V}, I_C = 1.6 \text{ A}$	200	—	—	
Collector-emitter saturation voltage		$V_{CE (sat)}$	$I_C = 1.6 \text{ A}, I_B = 32 \text{ mA}$	—	—	0.22	V
Base-emitter saturation voltage		$V_{BE (sat)}$	$I_C = 1.6 \text{ A}, I_B = 32 \text{ mA}$	—	—	1.10	V
Switching time	Rise time	t_r	See Figure 1. $V_{CC} \approx 24 \text{ V}, R_L = 15 \Omega$ $I_{B1} = 32 \text{ mA}, I_{B2} = -53 \text{ mA}$	—	63	—	ns
	Storage time	t_{stg}		—	560	—	
	Fall time	t_f		—	55	—	

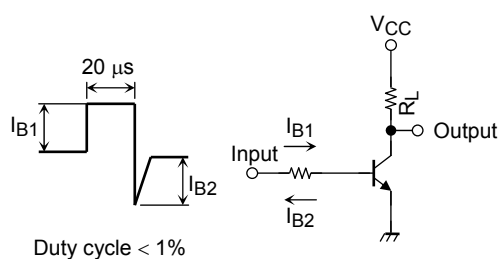
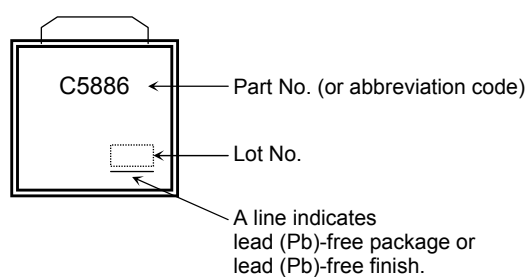
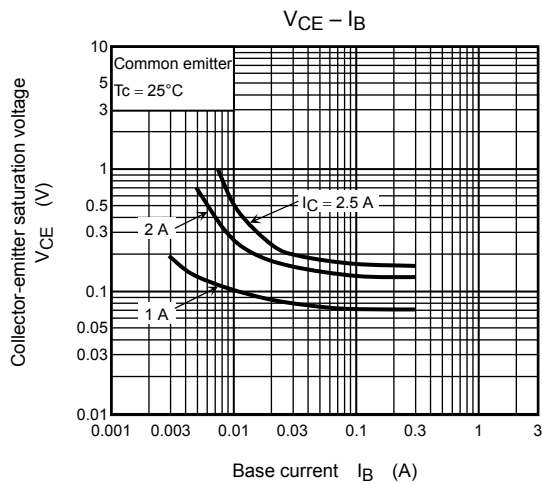
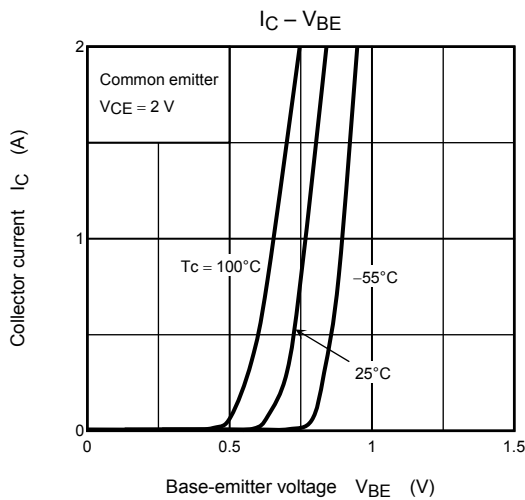
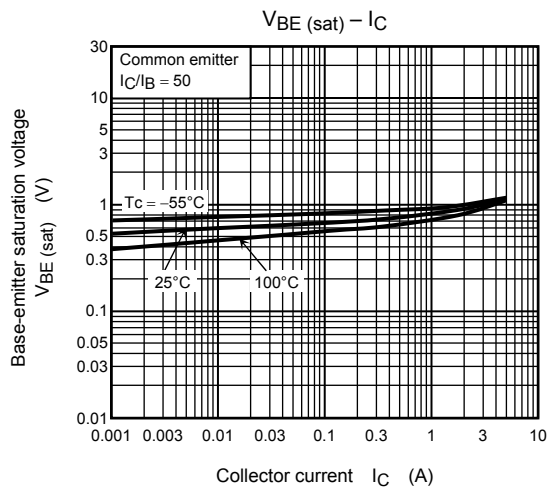
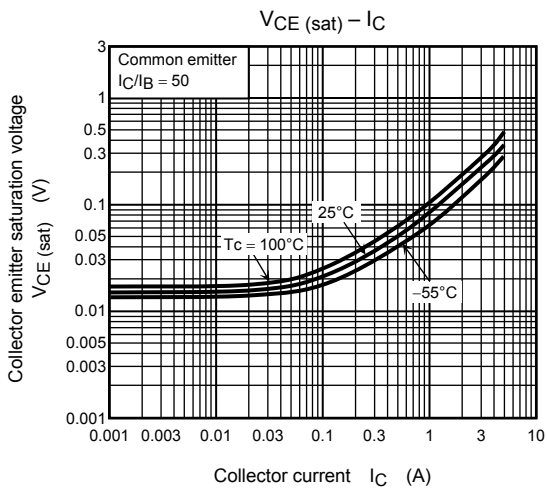
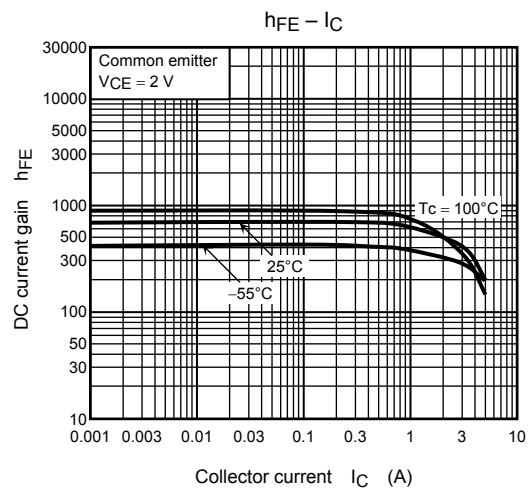
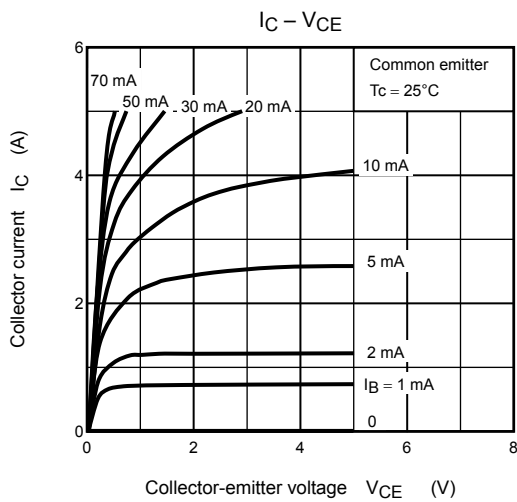
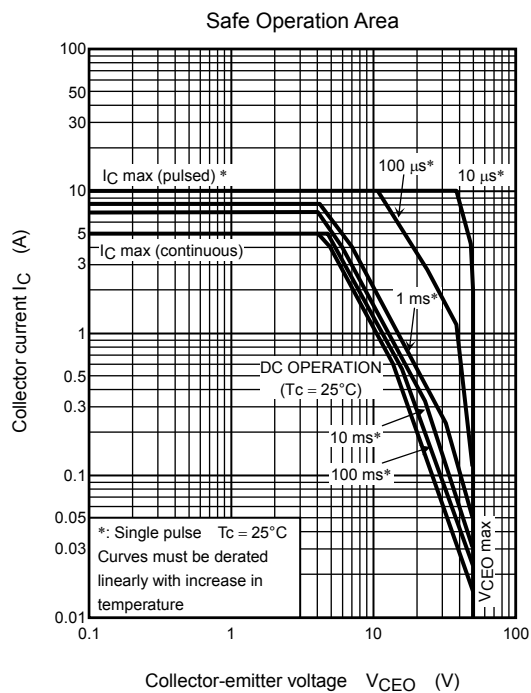
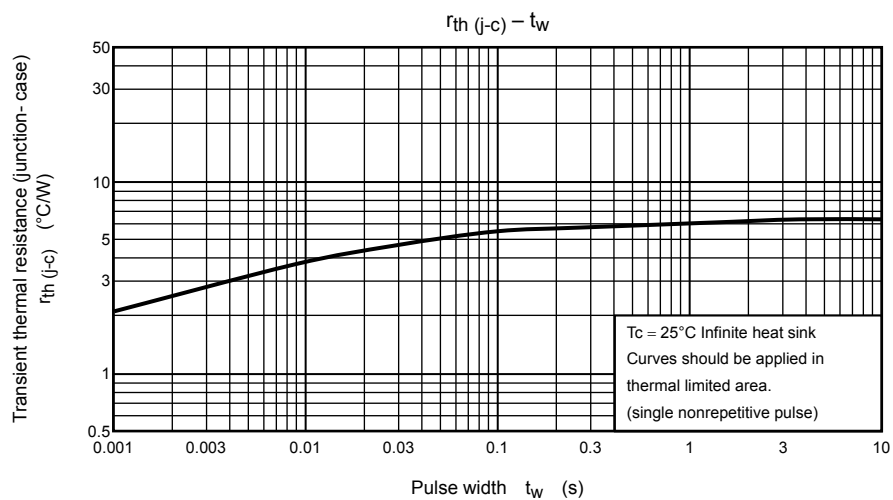


Figure 1 Switching Time Test Circuit & Timing Chart

Marking







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